TPS65631 双输出有源矩阵有机发光二极管 (AMOLED) 显示屏电源

1 特性

- 2.9V 至 4.5V 输入电压范围
- 4.6V 固定正输出电压
- 25ºC 至 85ºC 温度范围内，V_{POS} 精度 0.5%
- 单独的 V_{POS} 输出感测引脚
- -1.4V 至 -4.4V 的数字可编程负输出电压（缺省值 -4V）
- 支持的输出电流高达 250mA
- 出色的线路瞬态稳压
- 短路保护功能
- 热关断
- 采用 3.00mm x 3.00mm 12 引脚四方扁平无引线 (QFN) 封装

2 应用范围

AMOLED 显示屏

3 说明

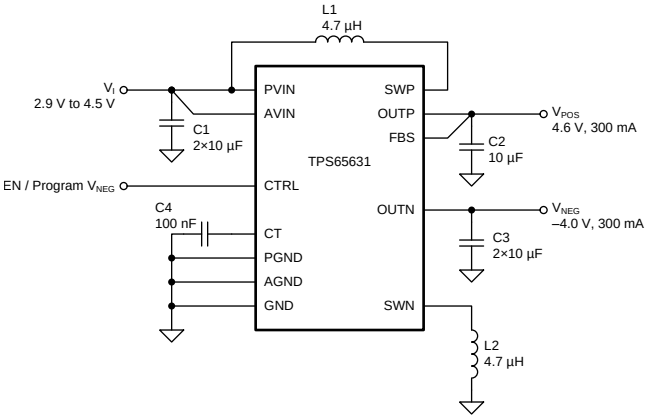
TPS65631 被设计用于驱动需要正负电源轨的 AMOLED（有源矩阵有机发光二极管）显示屏。 此器件集成了一个针对 V_{POS} 的升压转换器和一个针对 V_{NEG} 的反相降压升压转换器，非常适合于电池供电类产品。 数字控制引脚 (CTRL) 允许用数字步长设定负输出电压。 TPS65631 使用能够实现出色线路瞬态性能的创新技术。

器件信息(1)

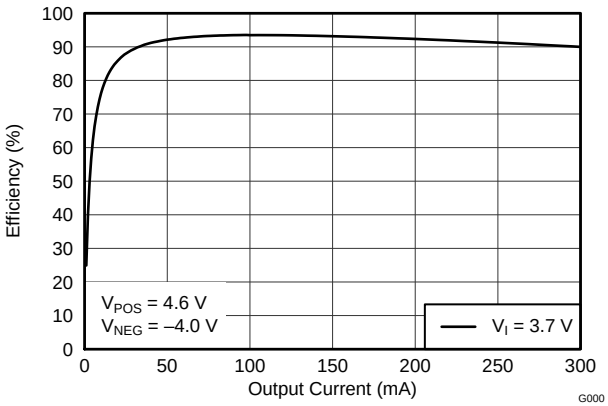
产品型号	封装	封装尺寸（标称值）
TPS65631	QFN (12)	3.00mm x 3.00mm

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

4 简化电路原理图



效率与输出电流间的关系



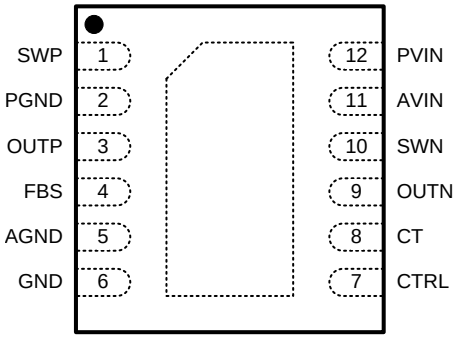
目录

5 修订历史记录

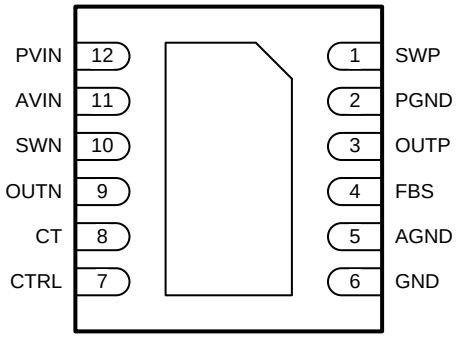
日期	修订版本	注释
2014 年 5 月	E	没有针对修订版本 E 的之前修订历史记录 - 首次公开发布

6 Pin Configuration and Functions

DPD PACKAGE
(TOP VIEW)



DPD PACKAGE
(BOTTOM VIEW)



Pin Functions

NAME	NO.	I/O	DESCRIPTION
AGND	5	—	Analog ground.
AVIN	11	—	Input supply voltage for internal analog circuits (both converters).
CT	8	I/O	Timing capacitor pin. Connect a capacitor between this pin and ground to control the time it takes for the output of the inverting buck-boost converter to ramp from one value of V_{NEG} to another.
CTRL	7	I	Control pin. Combined device enable and inverting buck-boost converter output voltage programming pin.
FBS	4	I	Feedback sense pin of the boost converter output voltage.
GND	6	—	Ground. (Note: it is possible to leave this pin floating without affecting device performance.)
PGND	2	—	Power ground of the boost converter.
PVIN	12	—	Input supply voltage pin for the inverting buck-boost converter.
SWN	10	O	Switch pin of the inverting buck-boost converter.
SWP	1	O	Switch pin of the boost converter.
OUTN	9	O	Rectifier pin of the inverting buck-boost converter.
OUTP	3	O	Rectifier pin of the boost converter.
Exposed Thermal Pad	13	—	Connect this pad to AGND and PGND.

7 Specifications

7.1 Absolute Maximum Ratings (1)

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Input voltage (2)	SWP, OUTP, FBS, PVIN, AVIN	–0.3	6	V
	OUTN	–0.3	–6	V
	SWN	–6	6	V
	CTRL	–0.3	5.5	V
	CT	–0.3	3.6	V
Operating junction temperature range, T_J		–40	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) With respect to GND pin.

7.2 Handling Ratings

			MIN	MAX	UNIT
T_{STG}	Storage temperature range		–65	150	°C
V_{ESD}	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	–2	2	kV
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	–500	500	V
		Machine model (MM) ESD stress voltage	–200	200	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process..

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

PARAMETER			MIN	NOM	MAX	UNIT
V_I	Input supply voltage range		2.9	3.7	4.5	V
V_O	Output voltage range	V_{POS}		4.6		V
		V_{NEG}	–4.4	–4	–1.4	
I_O	Output current range	I_{POS}			300	mA
		I_{NEG}			300	
T_A	Operating ambient temperature		–40	25	85	°C
T_J	Operating junction temperature		–40	85	125	°C

7.4 Thermal Information

THERMAL METRIC (1)		PD	UNIT
		12 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	51.5	°C/W
$R_{\theta JCtop}$	Junction-to-case (top) thermal resistance	47.1	
$R_{\theta JB}$	Junction-to-board thermal resistance	25.0	
ψ_{JT}	Junction-to-top characterization parameter	0.5	
ψ_{JB}	Junction-to-board characterization parameter	25.2	
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	4.4	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

7.5 Electrical Characteristics

V_I = 3.7 V, $V_{(CTRL)}$ = 3.7 V, V_{POS} = 4.6 V, V_{NEG} = –4.0 V, T_J = –40°C to 125°C, typical values are at T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
I_I	Shutdown current into AVIN and PVIN	CTRL pin connected to ground.		0.1		µA
V_{UVLO}	Undervoltage lockout threshold	V_I rising.			2.4	V
		V_I falling.			2.1	
BOOST CONVERTER						
V_O	Output voltage			4.6		V
	Output voltage tolerance	25°C ≤ T_A ≤ 85°C, no load	–0.5%		0.5%	
		–40°C ≤ T_A < 85°C, no load	–0.8%		0.8%	
$r_{DS(ON)}$	Switch (low-side) on-resistance	$I_{(SWP)}$ = 200 mA		200		mΩ
	Rectifier (high-side) on-resistance	$I_{(SWP)}$ = 200 mA		350		
	Switching frequency	I_O = 200 mA		1.7		MHz
	Switch current limit	Inductor valley current	0.8	1		A
	Short-circuit threshold voltage in operation	V_O falling		4.1		V
	Short-circuit detection time during operation			3		ms
	Output sense threshold voltage using OUTP	$V_{(OUTP)}$ - $V_{(FBS)}$ increasing		300		mV
	Output sense threshold voltage using FBS	$V_{(OUTP)}$ - $V_{(FBS)}$ decreasing		200		mV
	Input resistance of FBS	Between FBS pin and ground		4		MΩ
	Discharge resistance	CTRL pin connected to ground, I_O = 1 mA		30		Ω
	Line regulation	I_O = 200 mA		0.002		%/V
	Load regulation			0.01		%/A
INVERTING BUCK-BOOST CONVERTER						
V_O	Output voltage default			–4.0		V
	Output voltage range		–4.4		–1.4	
	Output voltage tolerance		–0.05		0.05	
$r_{DS(ON)}$	Switch (high-side) on-resistance	$I_{(SWN)}$ = 200 mA		200		mΩ
	Rectifier (low-side) on-resistance	$I_{(SWN)}$ = 200 mA		300		
	Switching frequency	I_O = 10 mA		1.7		MHz
	Switch current limit	V_I = 2.9 V	1.5	2.2		A
	Short-circuit threshold voltage during operation	Voltage drop from nominal V_O		500		mV
	Short-circuit threshold voltage during start-up		180	200	230	
t_{SCP}	Short-circuit detection time during start-up			10		ms
	Short-circuit detection time during operation			3		ms
	Discharge resistance	CTRL pin connected to ground, I_O = 1 mA		150		Ω
	Line regulation	I_O = 200 mA		0.006		%/V
	Load regulation			0.31		%/A
CTRL						
	High-level threshold voltage				1.2	V
	Low-level threshold voltage		0.4			V

Electrical Characteristics (continued)

V_I = 3.7 V, $V_{(CTRL)}$ = 3.7 V, V_{POS} = 4.6 V, V_{NEG} = –4.0 V, T_J = –40°C to 125°C, typical values are at T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Pull-down resistance		150	400	860	kΩ
OTHER						
$R_{(CT)}$	CT pin output resistance		150	300	500	kΩ
t_{INIT}	Initialization time			300	400	µs
t_{OFF}	Shut-down time		30		80	µs
t_{STORE}	Data storage time		30		80	µs
T_{SD}	Thermal shutdown temperature			145		°C

7.6 Timing Requirements

		MIN	TYP	MAX	UNIT
CTRL Interface					
t_{HIGH}	High-level pulse duration	2	10	25	µs
t_{LOW}	Low-level pulse duration	2	10	25	µs

7.7 Typical Characteristics

At T_A = 25°C, unless otherwise noted.

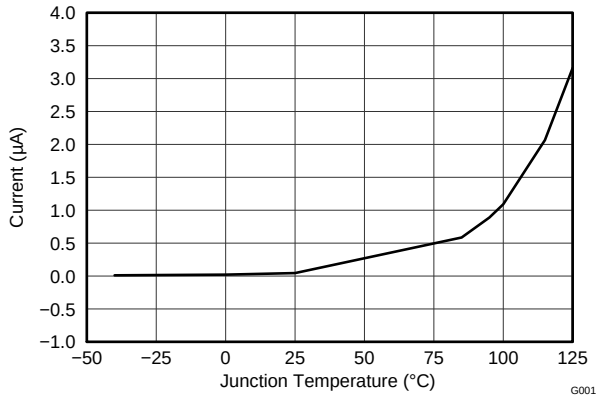


Figure 1. Shutdown Current into AVIN and PVIN

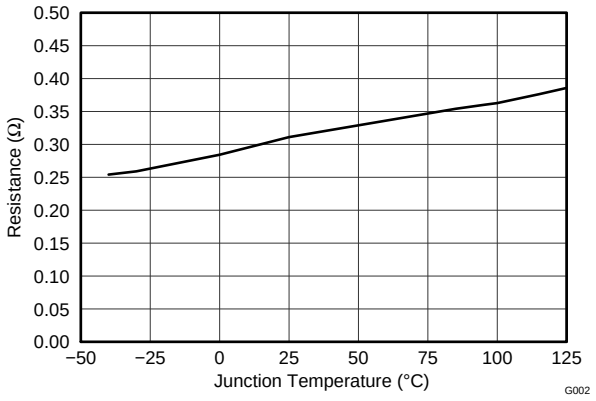


Figure 2. Boost Converter Switch $r_{DS(ON)}$

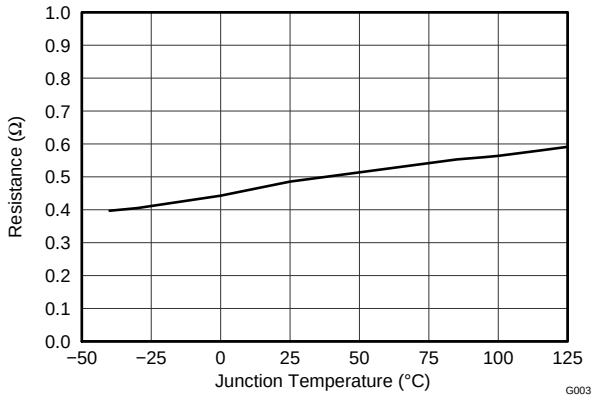


Figure 3. Boost Converter Rectifier $r_{DS(ON)}$

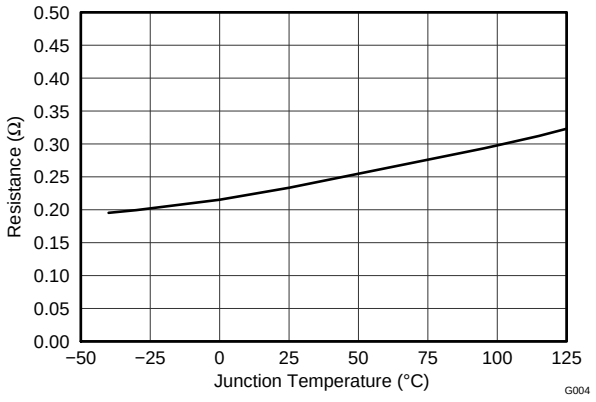


Figure 4. Inverting Buck-Boost Converter Switch $r_{DS(ON)}$

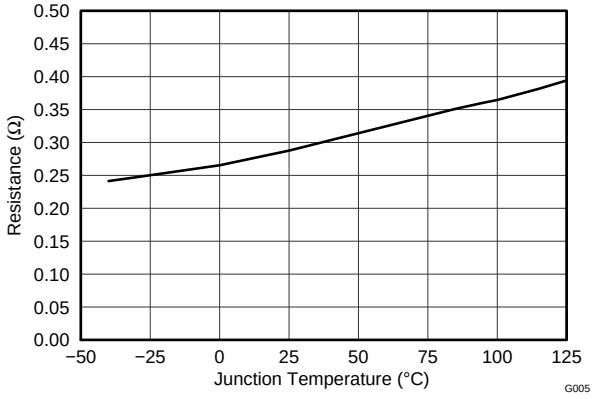


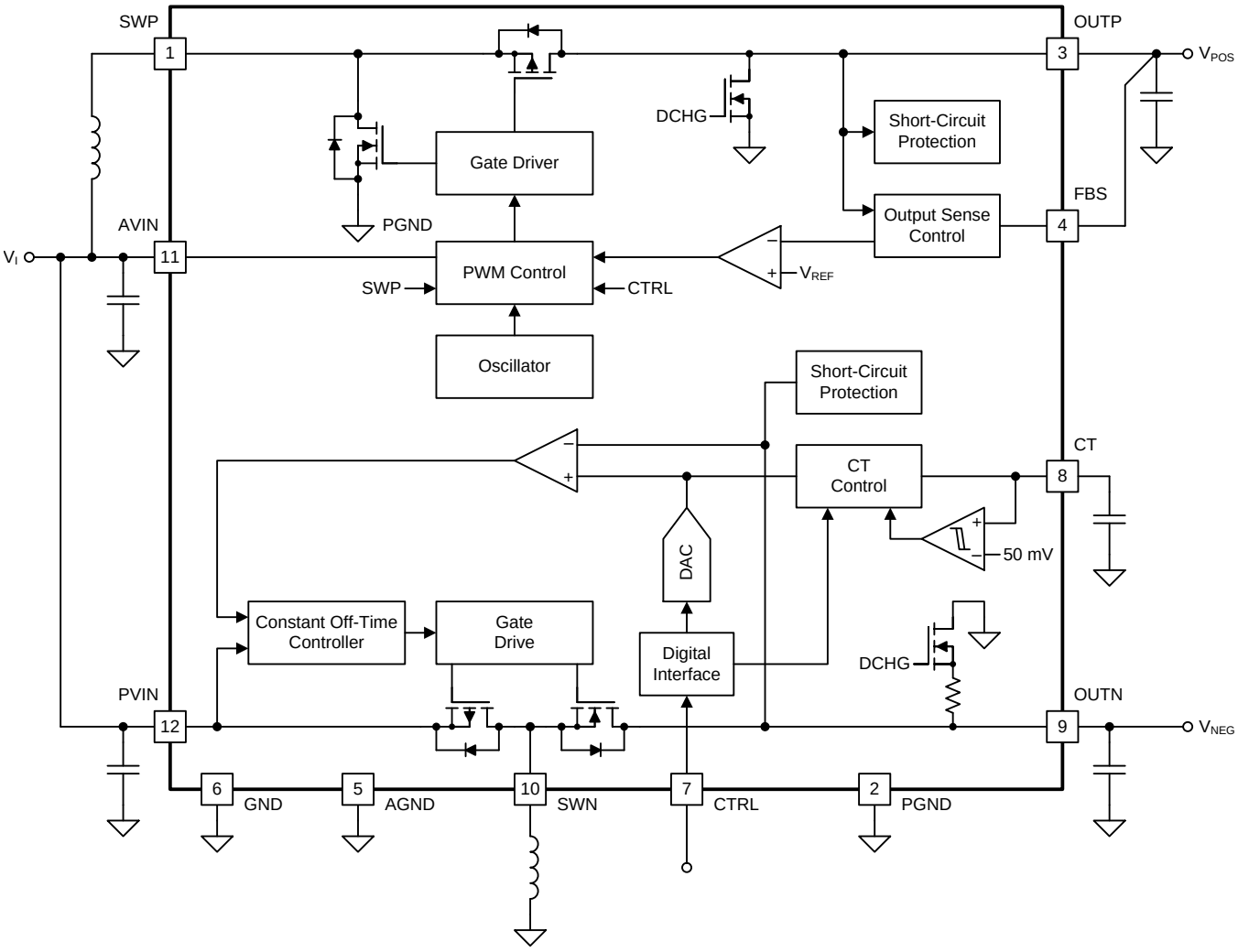
Figure 5. Inverting Buck-Boost Converter Rectifier $r_{DS(ON)}$

8 Detailed Description

8.1 Overview

The TPS65631 consists of a boost converter and an inverting buck boost converter. The V_{POS} output is fixed at 4.6 V and V_{NEG} output is programmable via a digital interface in the range of -1.4 V ~ -4.4 V, the default is -4 V. The transition time of V_{NEG} output is adjustable by the CT pin capacitor.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Boost Converter

The boost converter uses a fixed-frequency current-mode topology, and its output voltage (V_{POS}) is fixed at 4.6 V

For the highest output voltage accuracy, connect the output sense pin (FBS) directly to the positive pin of the output capacitor. If not used, the FBS pin can be left floating or connected to ground. If the FBS pin is not used, the boost converter senses its output voltage using the OUTP pin.

Feature Description (continued)

8.3.2 Inverting Buck-Boost Converter

The inverting buck-boost converter uses a constant-off-time peak-current mode topology. The converter's default output voltage (V_{NEG}) is –4 V, but it can be programmed to any voltage in the range –1.4 V to –4.4 V (see *Programming V_{NEG}*).

8.3.2.1 Programming V_{NEG}

The output voltage of the inverting buck-boost converter (V_{NEG}) can be programmed using the CTRL pin. If output voltage programming is not required, the CTRL pin can be used as a standard enable pin (see *Enable (CTRL)*).

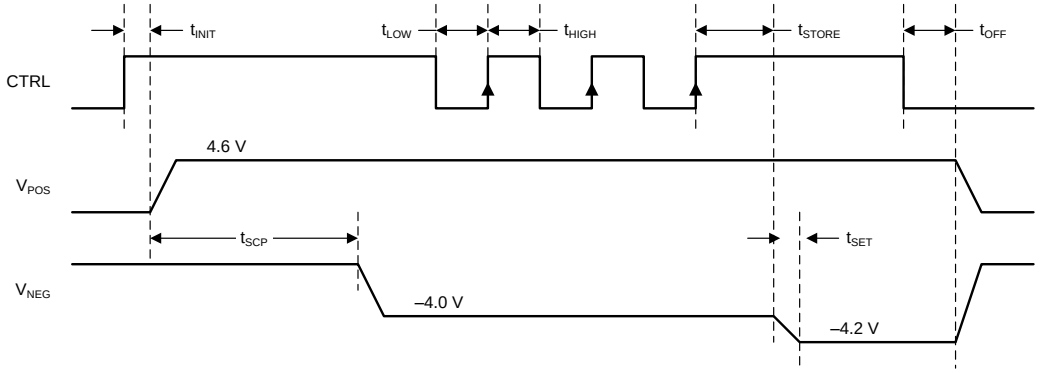


Figure 6. Programming V_{NEG} Using the CTRL Pin

When the CTRL pin is pulled high, the inverting buck-boost converter starts up with its default voltage of –4V. The device now counts the rising edges applied to the CTRL pin and sets the output voltage (V_{NEG}) according to Table 1. For the timing diagram shown in Figure 6, V_{NEG} is programmed to –4.2 V, since three rising edges are detected.

The CTRL interface is designed to work with pulses whose duration is between 2 µs and 25 µs. Pulses shorter than 2 µs or longer than 25 µs are not ensured to be recognized.

Table 1. Programming Table for V_{NEG}

Number of Rising Edges	V_{NEG}	Number of Rising Edges	V_{NEG}
0 / no pulses	–4 V	16	–2.9 V
1	–4.4 V	17	–2.8 V
2	–4.3 V	18	–2.7 V
3	–4.2 V	19	–2.6 V
4	–4.1 V	20	–2.5 V
5	–4.0 V	21	–2.4 V
6	–3.9 V	22	–2.3 V
7	–3.8 V	23	–2.2 V
8	–3.7 V	24	–2.1 V
9	–3.6 V	25	–2.0 V
10	–3.5 V	26	–1.9 V
11	–3.4 V	27	–1.8 V
12	–3.3 V	28	–1.7 V
13	–3.2 V	29	–1.6 V
14	–3.1 V	30	–1.5 V
15	–3.0 V	31	–1.4 V

8.3.2.2 Controlling the V_{NEG} Transition Time

The transition time (t_{set}) is the time required to move V_{NEG} from one voltage level to the next. Users can control the transition time by connecting a capacitor between the CT pin and ground. When the CT pin is left open or is connected to ground, the transition time is as short as possible. When a capacitor is connected to the CT pin, the transition time is determined by the time constant (τ) of the external capacitor ($C_{(CT)}$) and the internal resistance of the CT pin ($R_{(CT)}$). The output voltage V_{NEG} reaches 70% of its programmed value after 1τ.

An example is given below for the case when using 100 nF for $C_{(CT)}$.

$$\tau \approx t_{set(70\%)} = R_{(CT)} \times C_{(CT)} = 300\ k\Omega \times 100\ nF = 30\ ms \quad (1)$$

The output voltage V_{NEG} reaches its programmed value after approximately 3τ.

The external capacitor connected to the CT pin has no effect on the first programming of V_{NEG}, when the inverting buck-boost converter ramps its output to the default voltage as fast as possible. Figure 7 shows the detail of programming of the V_{NEG} transition time with the CT pin during start-up.

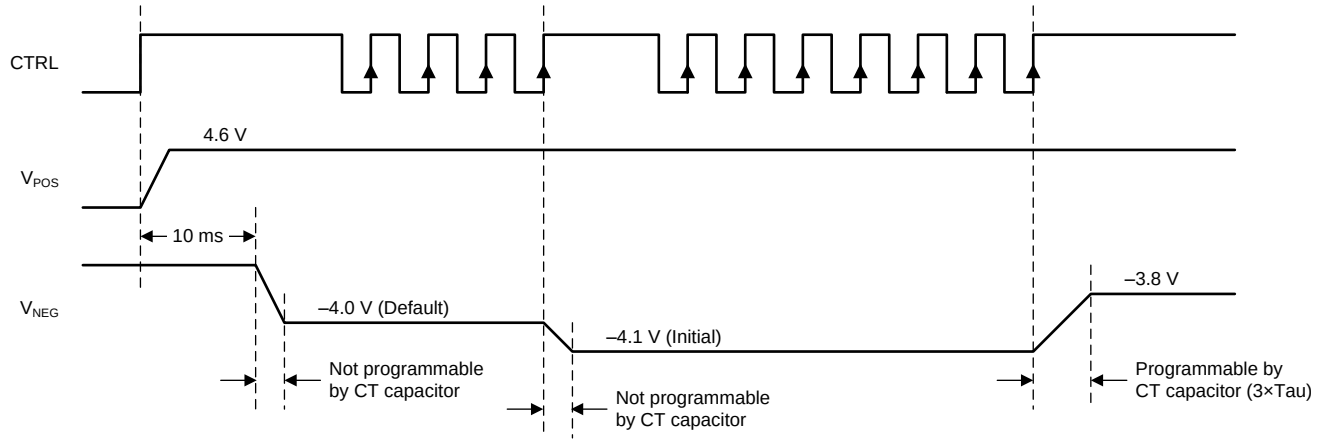


Figure 7. Programming the Transition Time of V_{NEG}

8.3.3 Soft-Start and Start-Up Sequence

The TPS65631 features a soft-start function to limit inrush current. When the device is enabled by a high-level signal applied to the CTRL pin, the boost converter starts switching with a reduced switch current limit. Ten milliseconds after the CTRL pin goes high, the inverting buck-boost converter starts with a default value of –4 V. A typical start-up sequence is shown in Figure 8.

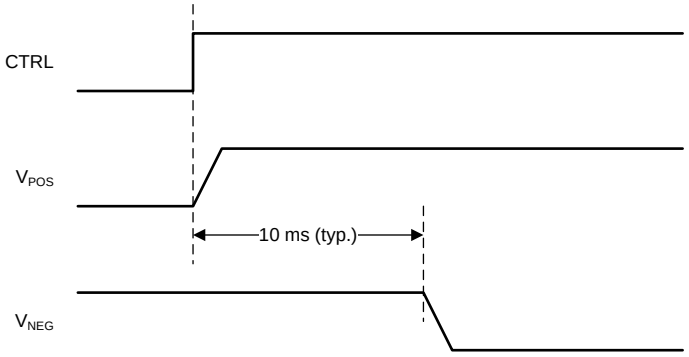


Figure 8. Typical Start-Up Sequence

8.3.4 Enable (CTRL)

The CTRL pin serves two functions. One is to enable and disable the device, and the other is to program the output voltage (V_{NEG}) of the inverting buck-boost converter (see *Programming V_{NEG}*). If the digital interface is not required, the CTRL pin can be used as a standard enable pin for the device, which will come up with its default value on V_{NEG} of –4 V. When CTRL is pulled high, the device is enabled. The device is shut down with CTRL low.

8.3.5 Undervoltage Lockout

The TPS65631 features an undervoltage lockout function that disables the device when the input supply voltage is too low for normal operation.

8.3.6 Short Circuit Protection

The TPS65631 is protected against short-circuits of V_{POS} and V_{NEG} to ground and to each other.

8.3.6.1 Short-Circuits During Normal Operation

During normal operation an error condition is detected if V_{POS} falls below 4.1 V for more than 3 ms or V_{NEG} is pulled above the programmed nominal output by 500 mV for longer than 3 ms. In either case the device enters shutdown mode: the converters are disabled and their outputs are disconnected from the input. To resume normal operation either cycle the input supply voltage or toggle the CTRL pin low and then high again.

8.3.6.2 Short-Circuits During Start-Up

During start up an error condition is detected if:

- V_{POS} is not in regulation 10 ms after a high-level is applied to the CTRL pin.
- V_{NEG} is higher than threshold level 10 ms after a high-level is applied to the CTRL pin.
- V_{NEG} is not in regulation 20 ms after a high-level is applied to the CTRL pin.

To resume normal operation either cycle the input supply voltage or toggle the CTRL pin low and then high again.

8.3.7 Output Discharge During Shutdown

The TPS65631 actively discharges its outputs during shutdown. Figure 9 shows the output discharge control.

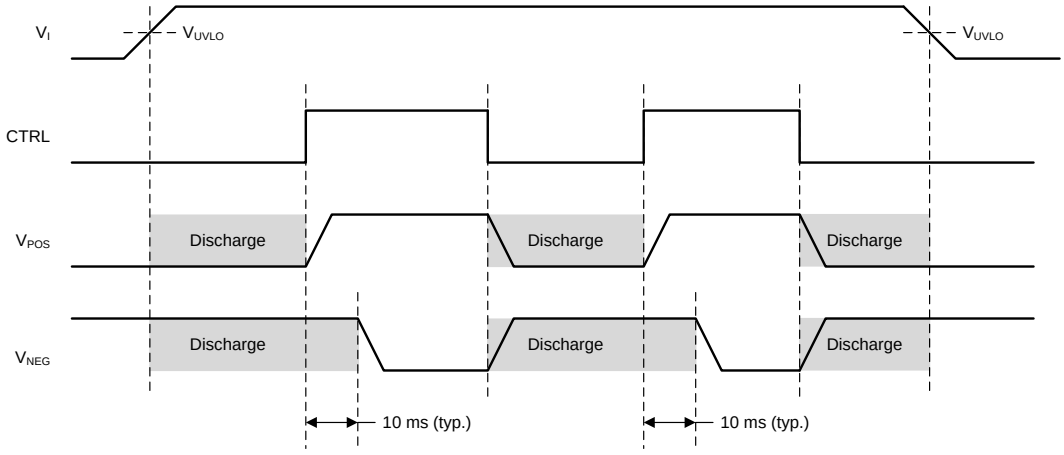


Figure 9. Active Discharge of V_{POS} and V_{NEG} During Shutdown

8.3.8 Thermal Shutdown

The TPS65631 enters thermal shutdown mode if its junction temperature exceeds 145°C (typical). During thermal shutdown mode none of the device functions are available. To resume normal operation, either cycle the input supply voltage or toggle the CTRL pin low and then high again.

8.4 Device Functional Modes

8.4.1 Operation with V_I < 2.9 V

The recommended minimum input supply voltage for full performance is 2.9 V. The device continues to operate with input supply voltages below 2.9 V; however, full performance is not guaranteed. The device does not operate with input supply voltages below the UVLO threshold.

8.4.2 Operation with $V_I \approx V_{POS}$ (Diode Mode)

The TPS65631 features a "diode" mode that enables it to regulate its output voltage even when the input supply voltage is close to V_{POS} (that is, too high for normal boost operation). When operating in diode mode the converter's high-side switch stops switching and its body diode is used as the rectifier. Boost converter efficiency is reduced when operating in diode mode. At low output currents (≈2 mA and below), the boost converter automatically transitions from pulse-width modulation to pulse-skip mode. This ensures that V_{POS} stays in regulation but increases the output voltage ripple on V_{POS}.

8.4.3 Operation with CTRL

When a low-level signal is applied to the CTRL pin the device is disabled and switching is inhibited. When the input supply voltage is above the UVLO threshold and a high-level signal is applied to the CTRL pin the device is enabled and its start-up sequence begins.

9 Applications and Implementation

9.1 Application Information

Figure 10 shows a typical application circuit suitable for supplying AMOLED displays in smartphone applications. The circuit is designed to operate from a single-cell Li-Ion battery and generates a positive output voltage V_{POS} of 4.6 V and a negative output voltage of –4 V. Both outputs are capable of supplying up to 300 mA of output current.

9.2 Typical Application

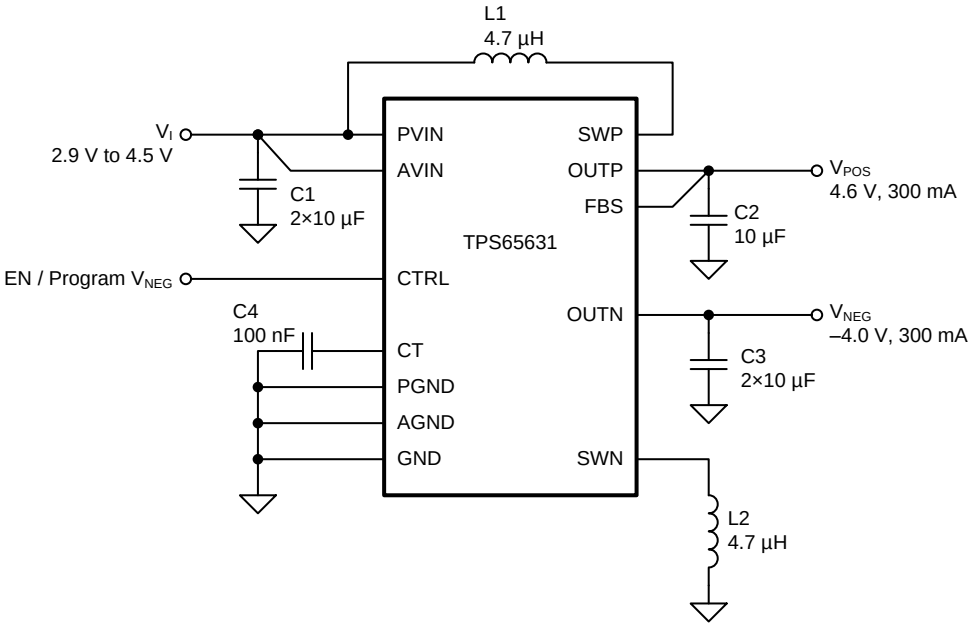


Figure 10. Typical Application Schematic

Typical Application (continued)

9.2.1 Design Requirements

For this design example, use the following input parameters.

Table 2. Design Parameters

DESIGN PARAMETER	EXAMPLE
Input voltage range	2.9 V to 4.5 V
Output voltage	V_{POS} = 4.6V, V_{NEG} = –4 V
Switching frequency	1.7 MHz

9.2.2 Detailed Design Procedure

In order to maximize performance, the TPS65631 has been optimized for use with a relatively narrow range of component values, and customers are strongly recommended to use the application circuit shown in Figure 10 with the components listed in Table 3 and Table 4.

9.2.2.1 Inductor Selection

The boost converter and inverting buck-boost converter have been optimized for use with 4.7 µH inductors, and it is recommended that this value be used in all applications. Customers using other values of inductor are strongly recommended to characterize circuit performance on a case-by-case basis.

Table 3. Inductor Selection

PARAMETER	VALUE	MANUFACTURER	PART NUMBER
L1, L2	4.7 µH	Coilmaster	MMPP252012-4R7N
		Toko	1239AS-H-4R7M
		ABCO	LPP252012-4R7N
		Coilcraft	XFL4020-4R7ML

9.2.2.2 Capacitor Selection

The recommended capacitor values are shown in Table 4. Applications using less than the recommended capacitance (e.g. to save PCB area) may experience increased voltage ripple. In general, the lower the output power, the lower the necessary capacitance.

Table 4. Capacitor Selection

PARAMETER	VALUE	MANUFACTURER	PART NUMBER
C1	2 × 10 µF	Murata	GRM21BR71A106KE51
C2	10 µF	Murata	GRM21BR71A106KE51
C3	2 × 10 µF	Murata	GRM21BR71A106KE51
C4	100 nF	Murata	GRM21BR71E104KA01

9.2.2.3 Stability

Applications using component values that differ significantly from those recommended in Table 3 and Table 4 should be checked for stability over the full range of operating conditions.

9.2.3 Application Curves

The performance shown in the following graphs was obtained using the circuit shown in Figure 10 and the external components shown in Table 3 and Table 4. The output voltage settings for these measurements were V_{POS} = 4.6 V and V_{NEG} = –4 V.

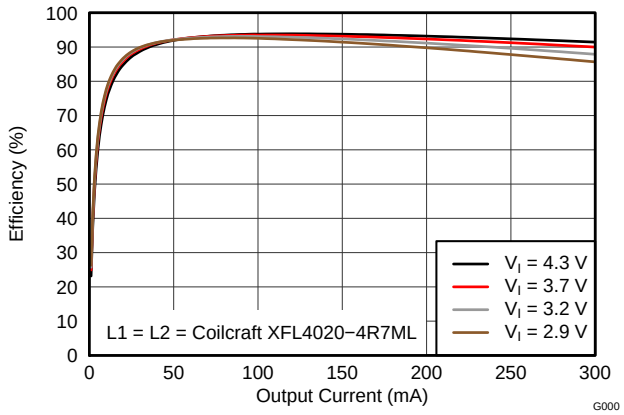


Figure 11. Efficiency vs. Output Current

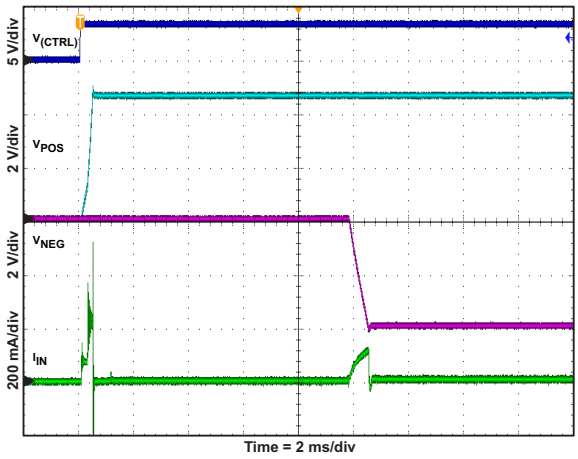


Figure 12. Start-Up Waveforms

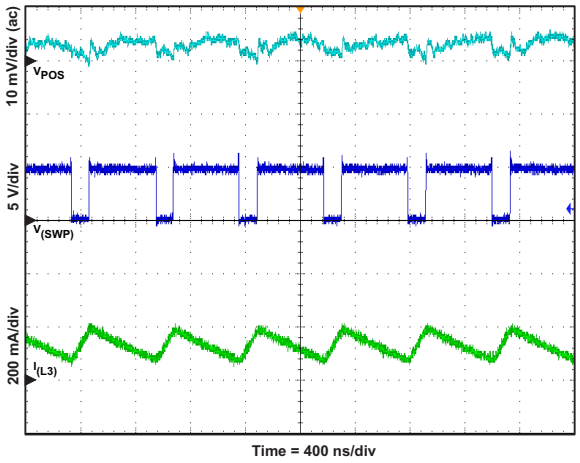


Figure 13. V_{POS} Switch Voltage, Inductor Current and Output Voltage Ripple (I_O = 100 mA)

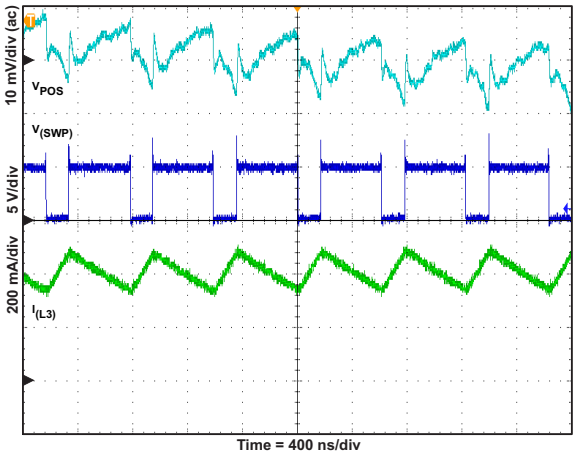


Figure 14. V_{POS} Switch Voltage, Inductor Current and Output Voltage Ripple (I_O = 300 mA)

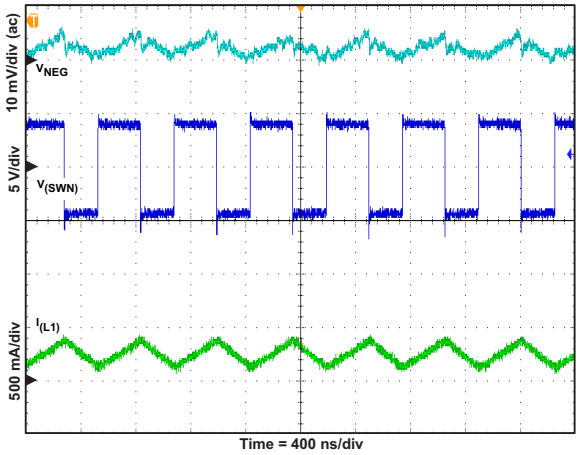


Figure 15. V_{NEG} Switch Voltage, Inductor Current and Output Voltage Ripple (I_O = 100 mA)

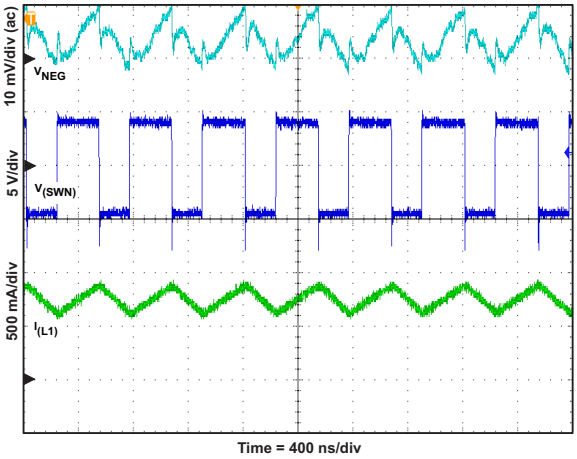


Figure 16. V_{NEG} Switch Voltage, Inductor Current and Output Voltage Ripple (I_O = 300 mA)

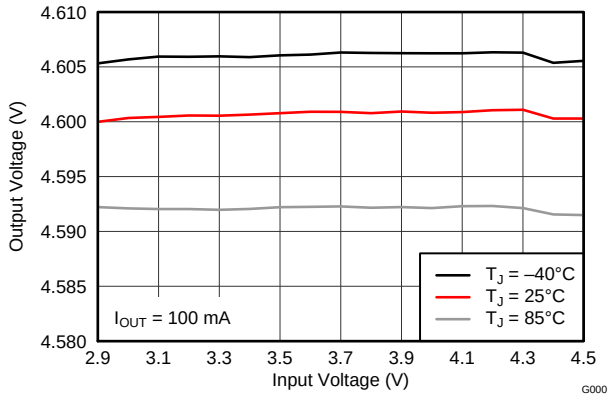


Figure 17. Boost Converter Line Regulation

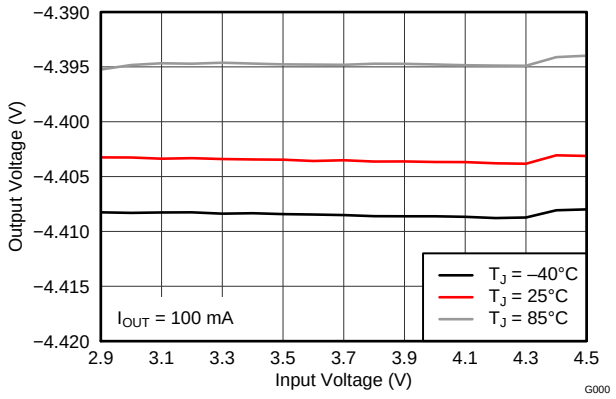


Figure 18. Inverting Buck-Boost Converter Line Regulation

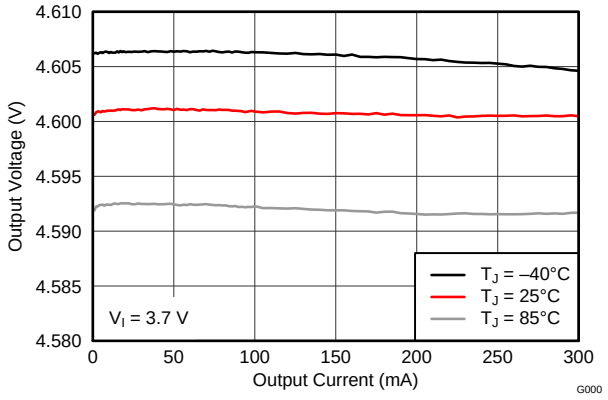


Figure 19. Boost Converter Load Regulation

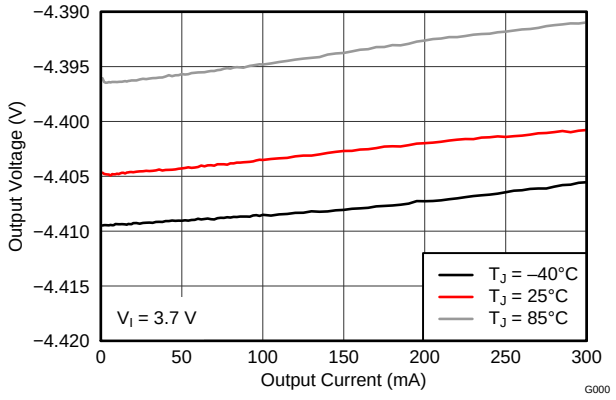


Figure 20. Inverting Buck-Boost Converter Load Regulation

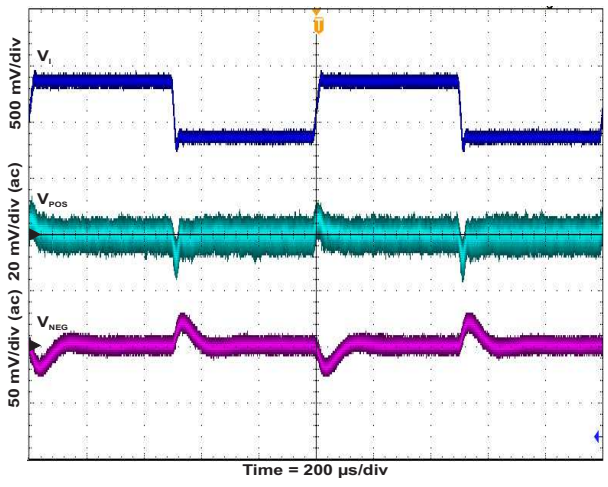


Figure 21. Line Transient Response

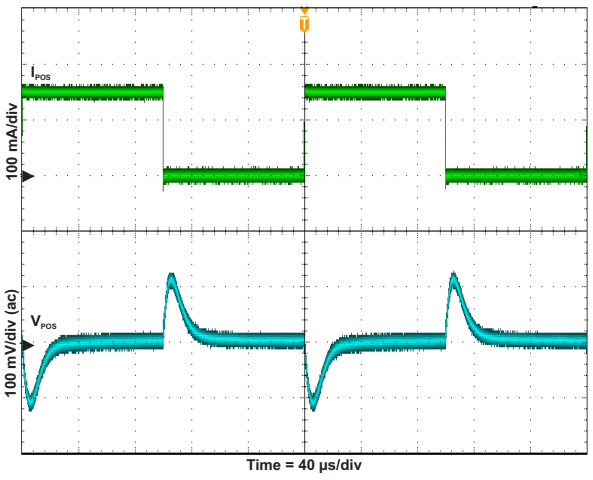


Figure 22. Boost Converter Load Transient Response

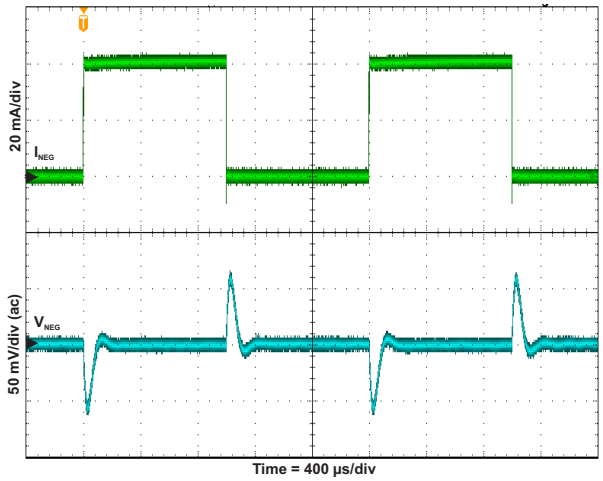


Figure 23. Inverting Buck-Boost Converter Load Transient Response

10 Power Supply Recommendations

The TPS65631 is designed to operate from an input voltage supply range between 2.9 V and 4.5 V. If the input supply is located more than a few centimeters from the TPS65631 additional bulk capacitance may be required. The 2×10 µF shown in the schematics in this data sheet are a typical choice for this function.

11 Layout

11.1 Layout Guidelines

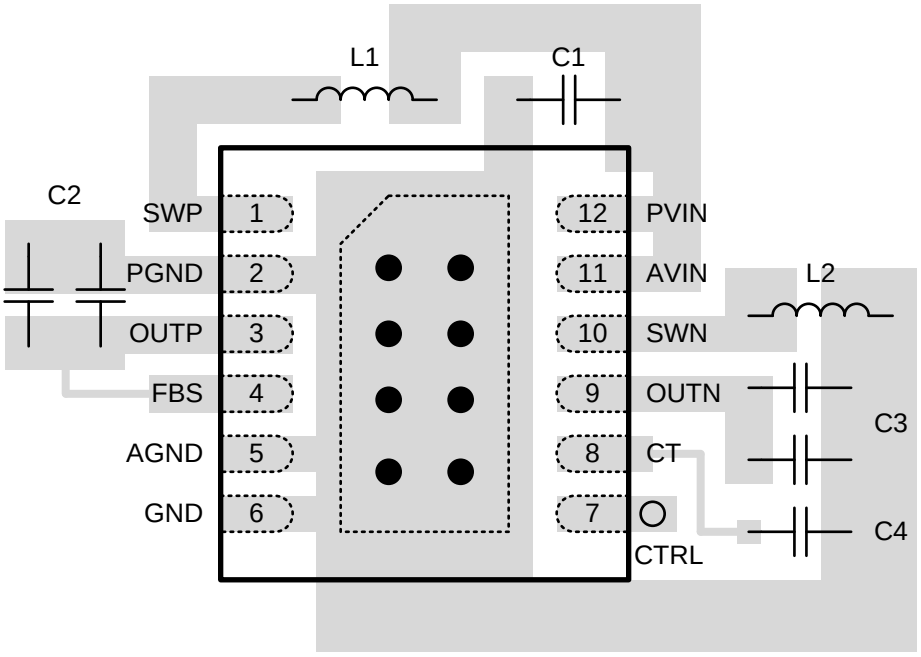
No PCB layout is perfect, and compromises are always necessary. However, following the basic principles listed below (in order of importance) should go a long way to achieving good performance:

- Route switching currents on the top layer using short, wide traces. Do not route these signals through vias, which have relatively high parasitic inductance and resistance.
- Place C1 as close as possible to pin 12.
- Place C2 as close as possible to pin 3.
- Place C3 as close as possible to pin 9.
- Place L1 as close as possible to pin 1.
- Place L2 as close as possible to pin 10.
- Use the thermal pad to join GND, AGND and PGND.
- Connect the FBS pin directly to the positive pin of C2, that is, keep this connection separate from the connection between OUTP and C2.
- Use a copper pour on layer 2 as a thermal spreader and connect the thermal pad to it using a number of thermal vias.

Figure 24 illustrates how a PCB layout following the above principles may be realized in practice.

11.2 Layout Example

Figure 24 shows the above principles implemented for the circuit of Figure 10.



○ Via to signal layer on internal or bottom layer.

● Thermal via to copper pour on internal or bottom layer.

Figure 24. PCB Layout Example

12 器件和文档支持

12.1 器件支持

12.1.1 第三方产品免责声明

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12.2 Trademarks

All trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms and definitions.

13 机械封装和可订购信息

以下页中包括机械封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS65631DPDR	Active	Production	WSON (DPD) | 12	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SDS
TPS65631DPDR.A	Active	Production	WSON (DPD) | 12	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SDS
TPS65631DPDR.B	Active	Production	WSON (DPD) | 12	3000 | LARGE T&R	-	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SDS

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

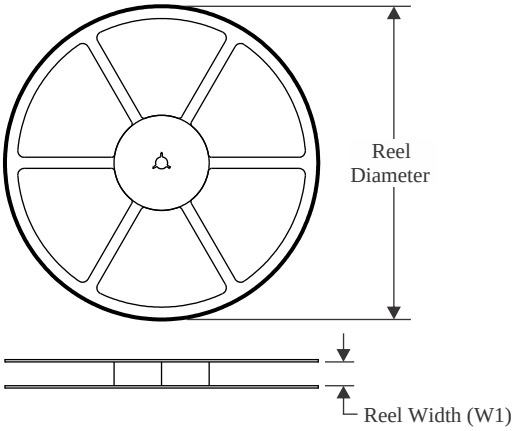
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

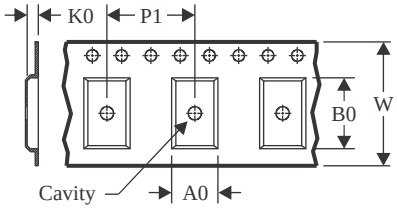
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

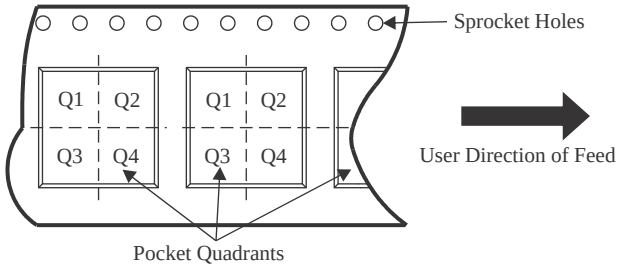


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

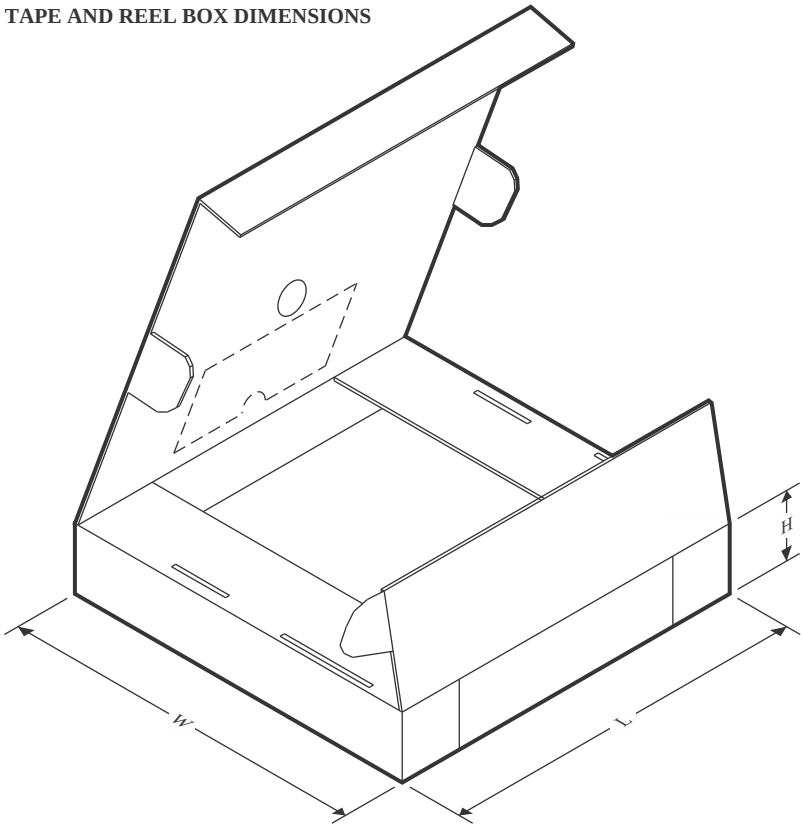
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS65631DPDR	WSON	DPD	12	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

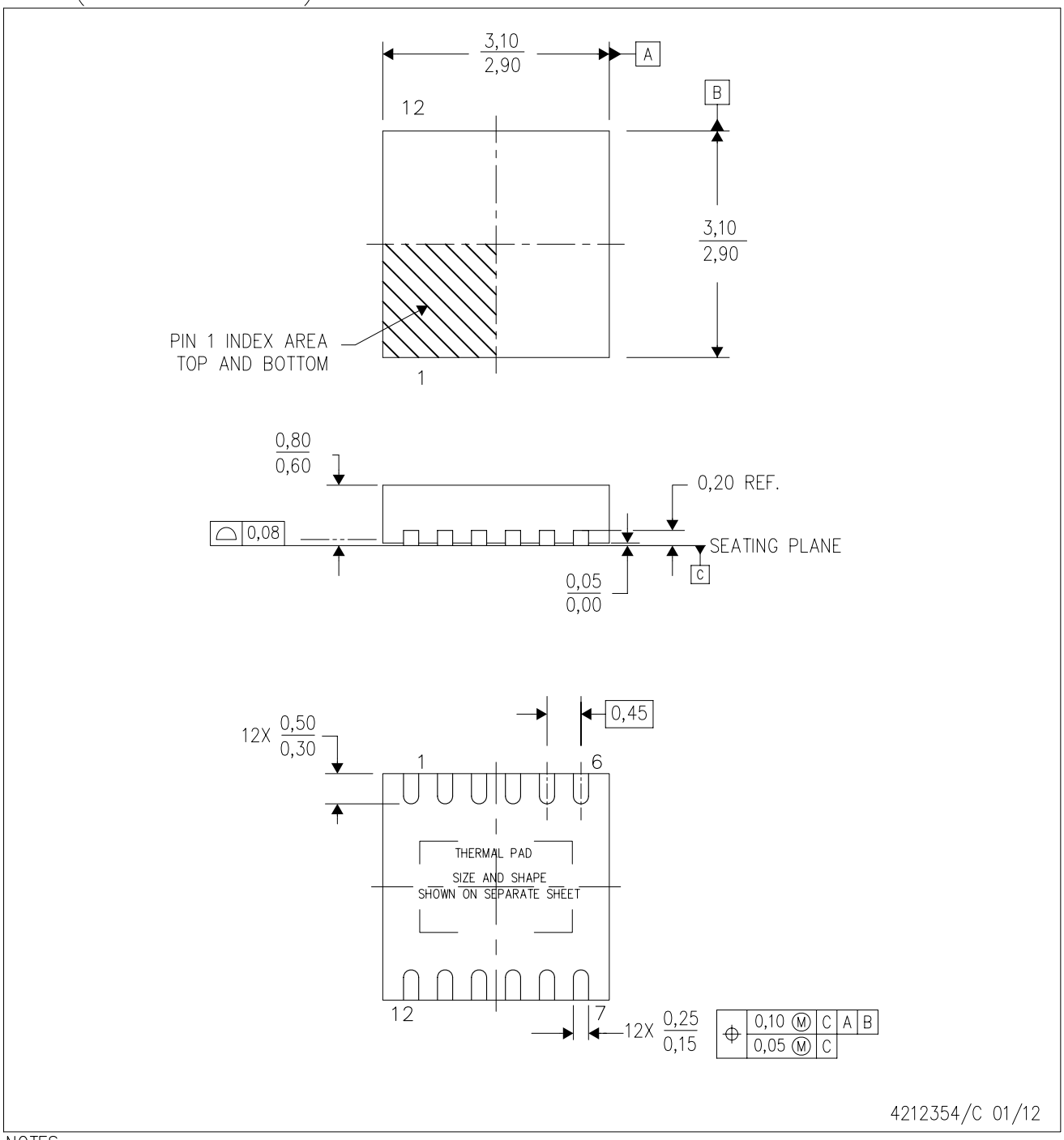
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS65631DPDR	WSON	DPD	12	3000	346.0	346.0	33.0

DPD (S–PWSON–N12) PLASTIC SMALL OUTLINE NO–LEAD



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Small Outline No–Lead (SON) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance, if present.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions, if present

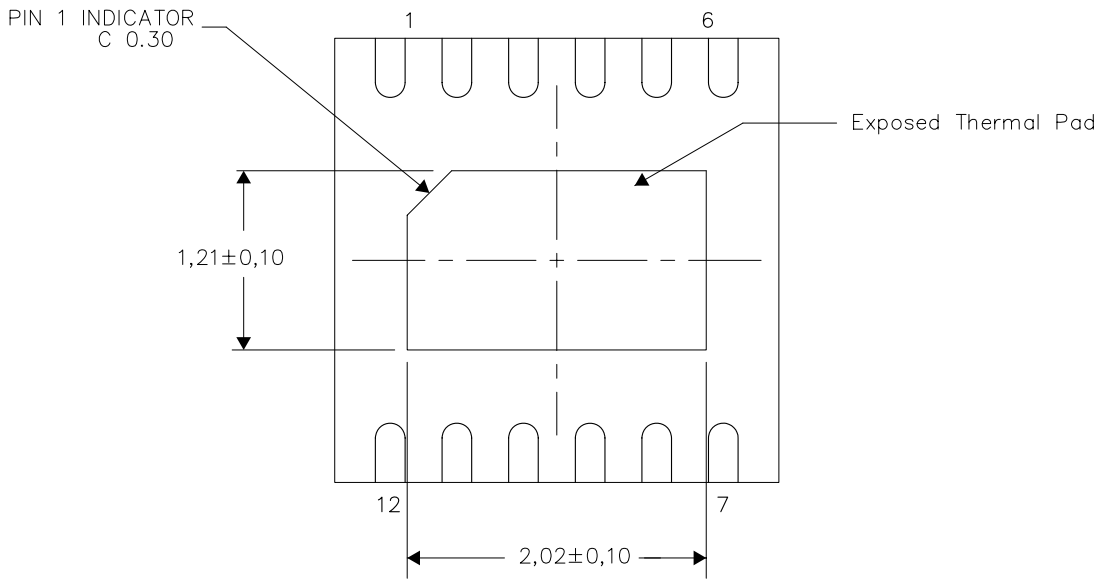
DPD (S–PUSON–N12) PLASTIC SMALL OUTLINE NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4212468/A 02/12

NOTE: All linear dimensions are in millimeters

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